

Silicon Bridge Rectifiers

W005--W10

FEATURES

- Rating to 1000V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Mounting Position: Any
- Glass passivated chip junctions



Lead-free

Maximum Ratings (@T_A = 25°C unless otherwise specified)

Characteristic	Symbol	W005	W01	W02	W04	W06	W08	W10	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @T _A =50°C	I _{F(AV)}	1.5							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	50.0							A

Thermal Characteristics

Characteristic	Symbol	W005	W01	W02	W04	W06	W08	W10	UNITS
Operating junction temperature range	T _J	- 55 ---- + 125							°C
Storage temperature range	T _{STG}	- 55 ---- + 150							°C

Electrical Characteristics (@T_A = 25°C unless otherwise specified)

Characteristic	Symbol	W005	W01	W02	W04	W06	W08	W10	UNITS
Maximum instantaneous forward voltage @1.0A	V _F	1.0							V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	5.0							μ A
		0.5							m A



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PACKAGE OUTLINE DIMENSIONS

WOM		
Dim	Min	Max
A	Ø 8.70	Ø 9.10
B	5.00	5.60
E	Ø0.60	Ø0.80
F	23.0min (长) \ 18.50min (短)	
F1	2.0min	
K	4.70	5.30
All Dimensions in mm		

PACKAGE INFORMATION

Device	Package	Shipping
W005--W10	WOM	1000Units/Box

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FIG.1 – PEAK FORWARD SURGE CURRENT

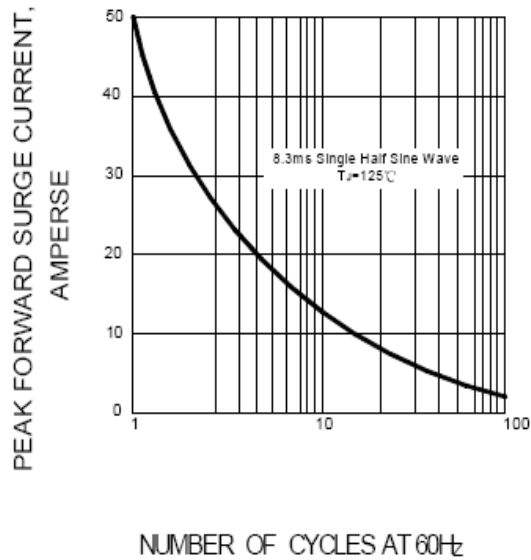


FIG.2 – FORWARD DERATING CURVE

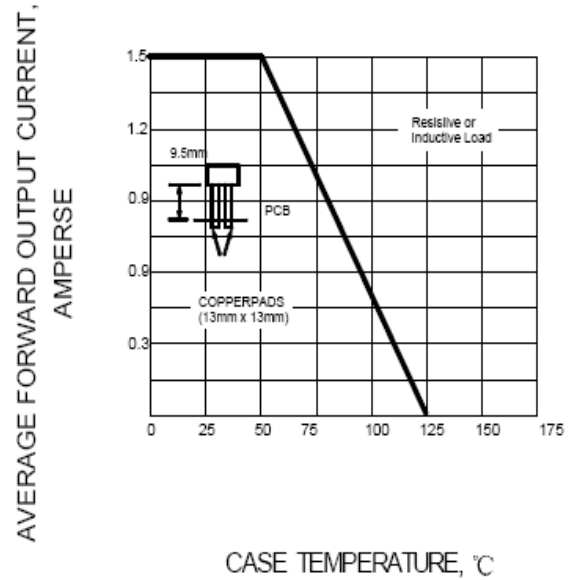


FIG.3 -- TYPICAL FORWARD CHARACTERISTIC

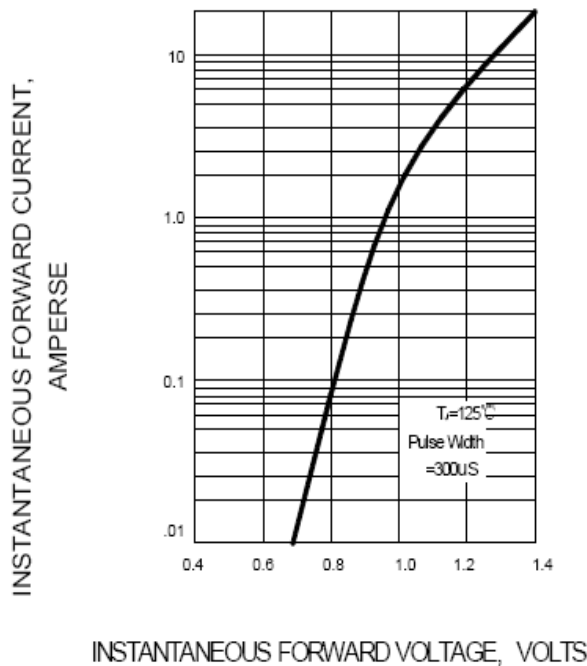


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

